# NSN 5961-01-352-3481

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## Inclosure Material:

Ceramic or plastic

#### **Overall Length:**

Between 9.4 millimeters and 10.42 millimeters

## **Overall Height:**

Between 2.19 millimeters and 2.38 millimeters

## **Overall Width:**

Between 6.35 millimeters and 6.73 millimeters

## Internal Configuration:

Field effect

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-252

Mounting Method:

Terminal

Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source

#### **Current Rating Per Characteristic:**

8.00 amperes zero-gate-voltage source current pascal

#### Power Rating Per Characteristic:

42.0 watts small-signal input power, common-collector preset

#### **Terminal Type And Quantity:**

3 pin

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0